TYPICAL DEVICE CHARACTERISTICS

MAXIMUM RATINGS @ 25°C Unless Otherwise Specified			
PARAMETER	SYMBOL	VALUE	UNITS
Unidirectional: Peak Pulse Power (tp = 8/20µs) - See Figure 1	P_{PP}	500	Watts
Bidirectional: Peak Pulse Power (tp = 8/20µs) - See Figure 1	P_{PP}	400	Watts
Operating Temperature	T_L	-55 to 150	°C
Storage Temperature	T_{STG}	-55 to 150	°C

ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless Otherwise Specified						
PART NUMBER (Note 1)	DEVICE MARKING	RATED STAND-OFF VOLTAGE V_{WM} VOLTS	MINIMUM BREAKDOWN VOLTAGE @ 1mA $V_{(BR)}$ VOLTS	MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ IP = 1A V_C VOLTS	MAXIMUM LEAKAGE CURRENT @V_{WM} I_D µA	TYPICAL CAPACITANCE @0V, 1MHz C pF
PSD03	A	3.3	4.0	6.5	125	500
PSD03C	G	3.3	4.0	7.0	125	200
PSD05	B	5.0	6.0	9.8	10	350
PSD05C	H	5.0	6.0	9.8	10	175
PSD08	C	8.0	8.5	13.4	10	250
PSD08C	J	8.0	8.5	13.4	10	150
PSD12	D	12.0	13.3	19.0	1	150
PSD12C	K	12.0	13.3	19.0	1	50
PSD15	E	15.0	16.7	24.0	1	100
PSD15C	L	15.0	16.7	24.0	1	40
PSD18	18	18.0	20.0	29.0	1	90
PSD18C	N	18.0	20.0	29.0	1	40
PSD24	F	24.0	26.7	43.0	1	88
PSD24C	M	24.0	26.7	43.0	1	40
PSD36	R	36.0	40.0	60.0	1	75
PSD36C	T	36.0	40.0	60.0	1	35

NOTES
1. Part numbers with an additional "C" suffix are bidirectional devices, i.e., PSD05**C**.

TYPICAL DEVICE CHARACTERISTICS

FIGURE 1
PEAK PULSE POWER VS PULSE TIME

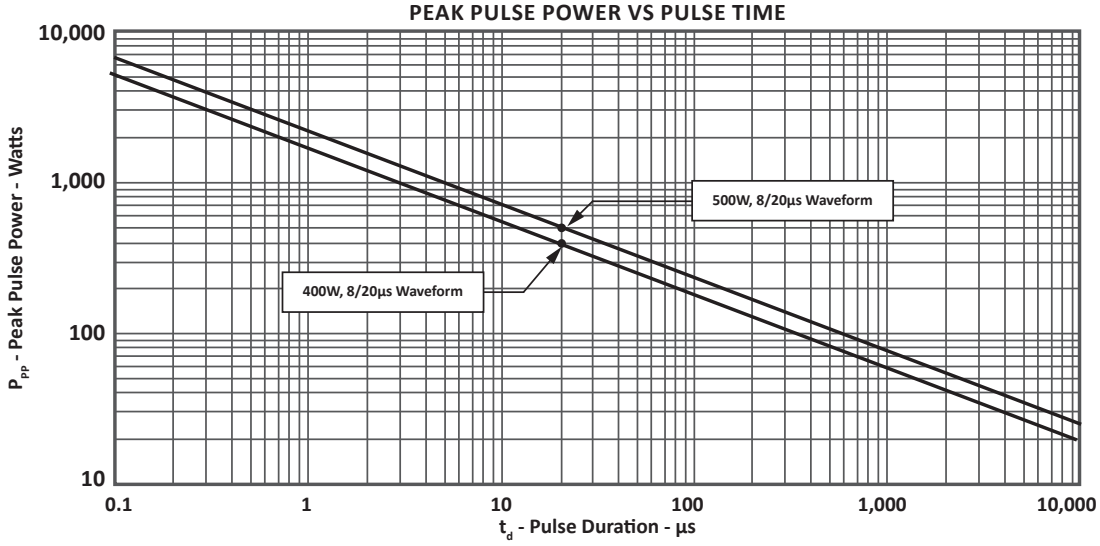


FIGURE 2
PULSE WAVE FORM

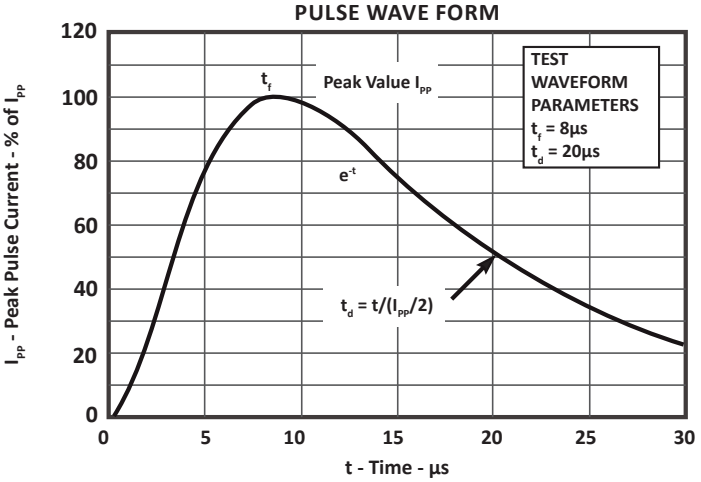
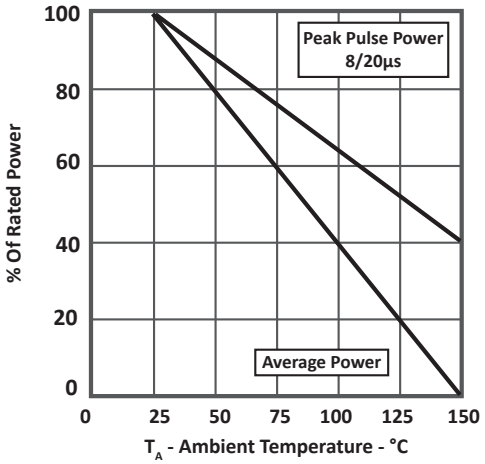
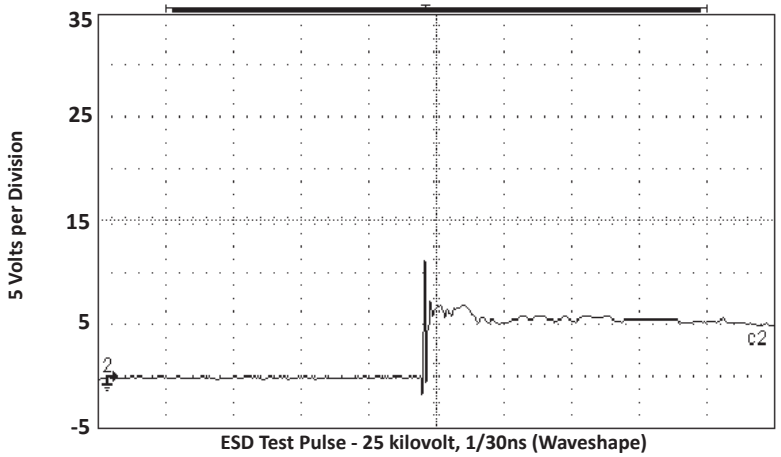


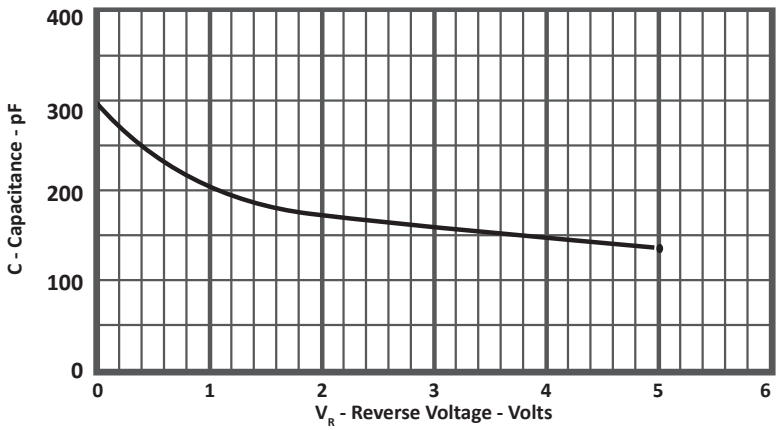
FIGURE 3
POWER DERATING CURVE



TYPICAL DEVICE CHARACTERISTICS

FIGURE 4
OVERSHOOT & CLAMPING VOLTAGE FOR PSD03





TYPICAL DEVICE CHARACTERISTICS

FIGURE 6
PSD03 FORWARD TLP
Leakage Current @ Pulse (I) - µA
Leakage Test Voltage = 0.5V

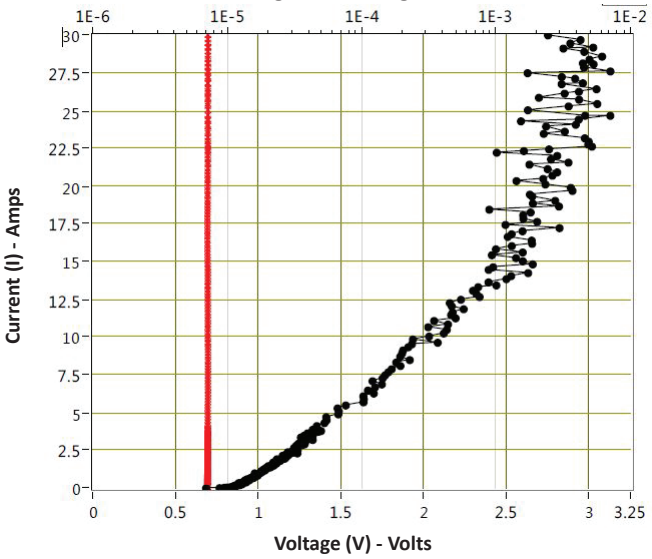
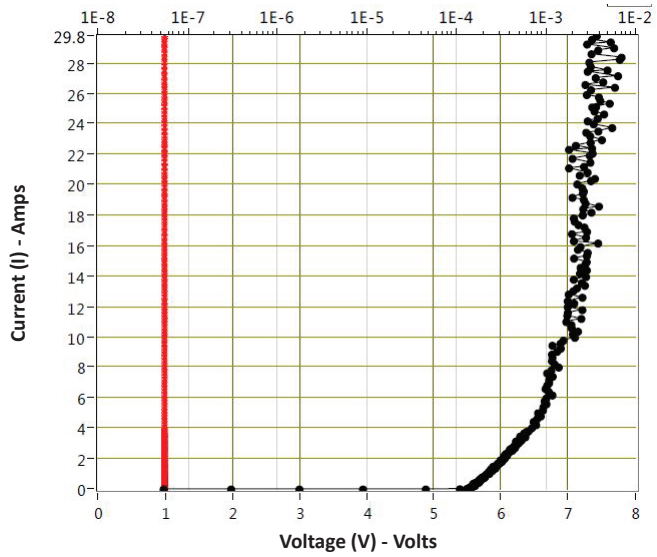


FIGURE 7
PSD03 REVERSE TLP
Leakage Current @ Pulse (I) - µA
Leakage Test Voltage = 0.5V



Note: Indicative TLP performance- for reference only

TYPICAL DEVICE CHARACTERISTICS

FIGURE 8
PSD36 FORWARD TLP
Leakage Current @ Pulse (I) - µA
Leakage Test Voltage = 0.5V

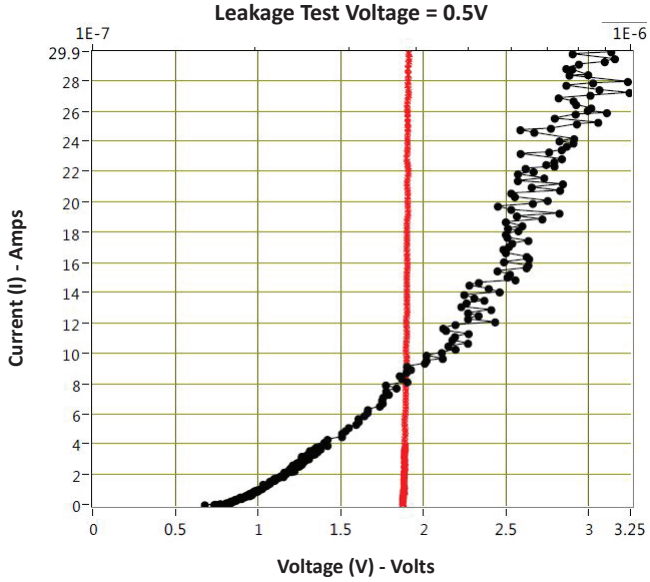
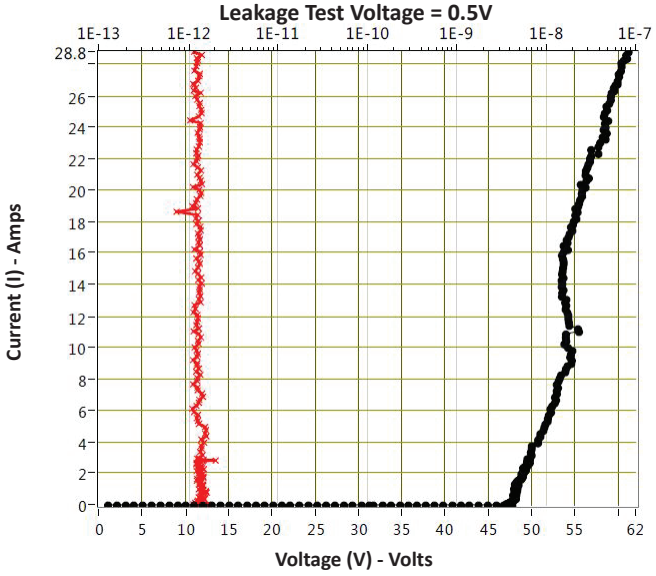


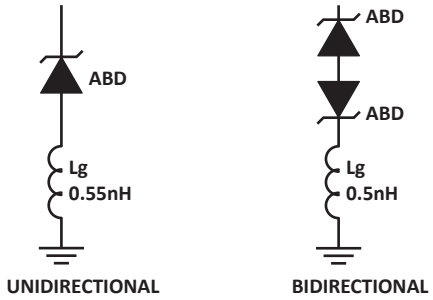
FIGURE 9
PSD36 REVERSE TLP
Leakage Current @ Pulse (I) - µA
Leakage Test Voltage = 0.5V



Note: Indicative TLP performance- for reference only

SPICE MODEL

FIGURE 1
SPICE MODEL FOR



ABD - Avalanche Breakdown Diode (TVS)
Lg - Lead Inductance

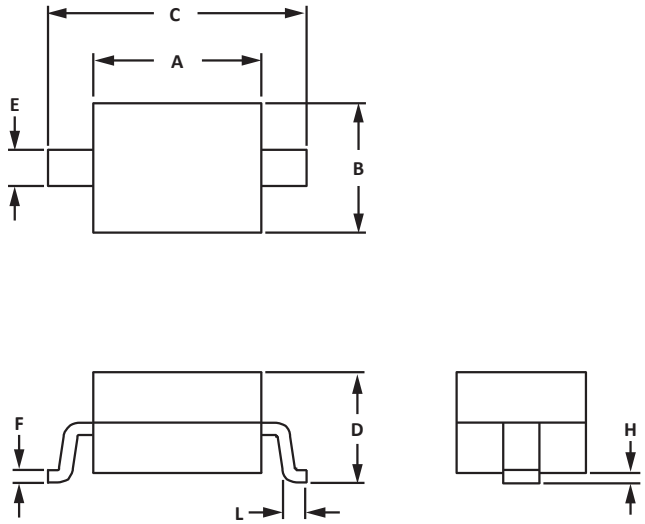
TABLE 1 - SPICE PARAMETERS		
PARAMETER	**UNIT**	**ABD(TVS)**
BV	V	See Table 2
IBV	µA	1
C_{jo}	pF	See Table 2
I_s	A	See Table 2
Vj	V	0.6
M	-	0.33
N	-	1
R_s	Ohms	See Table 2
TT	s	1E-8
EG	eV	1.11

TABLE 2 - ABD SPECIFIC SPICE PARAMETERS				
PART NUMBER	**B_V(VOLTS)**	**C_{jo}(pF)**	**I_s (AMPS)**	**Rs(OHMS)**
PSD03	4.0	438	1E-11	0.21
PSD05	6.0	284	1E-11	0.14
PSD08	8.5	146	1E-11	0.28
PSD12	13.3	123	1E-13	0.40
PSD15	16.7	102	1E-13	0.52
PSD24	26.7	61	1E-13	1.54
PSD03C	4.5	219	1E-11	0.21
PSD05C	6.0	142	1E-11	0.14
PSD08C	8.5	73	1E-11	0.28
PSD12C	13.3	62	1E-13	0.40
PSD15C	16.7	51	1E-13	0.52
PSD24C	26.7	30	1E-13	1.54

SOD-323 PACKAGE INFORMATION

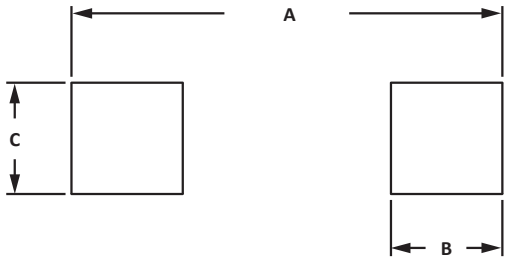
OUTLINE DIMENSIONS				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.60	1.90	0.063	0.075
B	1.15	1.45	0.045	0.057
C	2.39	2.70	0.094	0.106
D	0.80	1.10	0.031	0.043
E	0.25	0.40	0.010	0.016
F	0.10	0.20	0.004	0.008
H	-	0.10	-	0.004
L	0.20	-	0.008	-

NOTES
1. Controlling dimension: millimeters.
2. Dimensioning and tolerances per ANSI Y14.5M, 1985.
3. Dimensions are exclusive of mold flash and metal burrs.

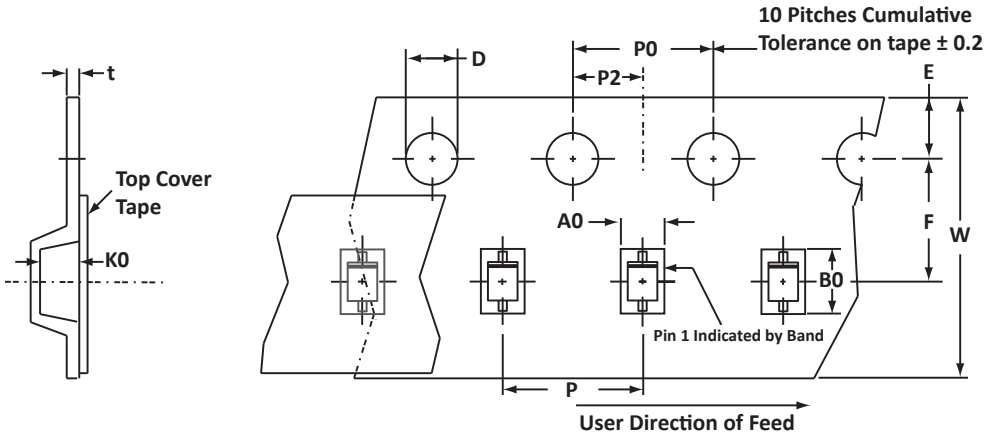


PAD LAYOUT DIMENSIONS				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.87	3.12	0.113	0.123
B	0.66	0.91	0.026	0.036
C	0.66	0.91	0.026	0.036

NOTES
1. Controlling dimension: millimeters.



TAPE AND REEL



SPECIFICATIONS												
REEL DIA.	TAPE WIDTH	A0	B0	K0	D	E	F	W	P0	P2	P	tmax
178mm (7")	8mm	1.55 ± 0.10	2.90 ± 0.10	1.35 ± 0.10	1.50 ± 0.10	1.75 ± 0.10	3.50 ± 0.05	8.00 ± 0.30	4.00 ± 0.10	2.00 ± 0.05	4.00 ± 0.10	0.25

NOTES
1. Dimensions are in millimeters.
2. Surface mount product is taped and reeled in accordance with EIA-481.
3. Suffix - T7 = 7" Reel - 3,000 pieces per 8mm tape.
4. Marking on Part - marking code (see page 2), polarity band (Unidirectional Only).

ORDERING INFORMATION					
BASE PART NUMBER (xx = Voltage)	LEADFREE SUFFIX	TAPE SUFFIX	QTY/REEL	REEL SIZE	TUBE QTY
PSDxx/PSDxxC	-LF	-T7	3,000	7"	n/a
This device is only available in a Lead-Free configuration.					

COMPANY INFORMATION

COMPANY PROFILE

In business more than 25 years, ProTek Devices™ is a privately held semiconductor company. The company offers a product line of overvoltage protection and overcurrent protection components. These include transient voltage suppressor array (TVS arrays) avalanche breakdown diode, steering diode TVS array and electronics SMD chip fuses. These components deliver circuit protection in electronic systems from numerous overvoltage and overcurrent events. They include lightning; electrostatic discharge (ESD); nuclear electromagnetic pulses (NEMP); inductive switching; and electromagnetic interference (EMI) / radio frequency interference (RFI). ProTek Devices also offers LED wafer die for ESD protection and related high frequency products. ProTek Devices is ISO 9001:2015 certified.

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